

MOS FIELD EFFECT TRANSISTOR 2SK3424

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3424 is N-Channel MOS FET device that features a low on-state resistance and excellent switching characteristics, designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

- 4.5 V drive available
- · Low on-state resistance $R_{DS(on)1} = 11.5 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = 10 \text{ V, Ip} = 24 \text{ A)}$
- · Low gate charge $Q_G = 34 \text{ nC TYP.}$ (ID = 48 A, VDD = 24 V, VGS = 10 V)
- · Built-in gate protection diode
- · Surface mount device available

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	30	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±48	Α
Drain Current (Pulse) Note	D(pulse)	±192	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	1.5	W
Total Power Dissipation (Tc = 25°C)	P _{T2}	50	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note PW \leq 10 μ s, Duty Cycle \leq 1%

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3424	TO-220AB		
2SK3424-ZK	TO-263(MP-25ZK)		
2SK3424-ZJ	TO-263(MP-25ZJ)		

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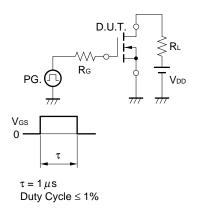
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

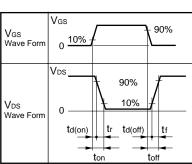


ELECTRICAL CHARACTERISTICS(TA = 25°C)

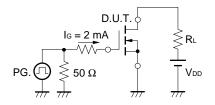
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	Ioss	V _{DS} = 30 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	V _G S(off)	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 24 A	13			S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 24 A		7.7	11.5	mΩ
	RDS(on)2	Vgs = 4.5 V, ID = 24 A		10.5	17.0	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		1900		pF
Output Capacitance	Coss	V _G S = 0 V		580		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		270		pF
Turn-on Delay Time	td(on)	VDD = 15 V , ID = 24 A		14		ns
Rise Time	tr	V _{GS(on)} = 10 V		13		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		61		ns
Fall Time	tf			22		ns
Total Gate Charge	QG	V _{DD} = 24 V		34		nC
Gate to Source Charge	Qgs	V _G S = 10 V		6.4		nC
Gate to Drain Charge	Q _{GD}	ID = 48 A		9.1		nC
Diode Forward Voltage	V _{F(S-D)}	IF = 48 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 48 A, VGS = 0 V		34		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		26		nC

TEST CIRCUIT 1 SWITCHING TIME

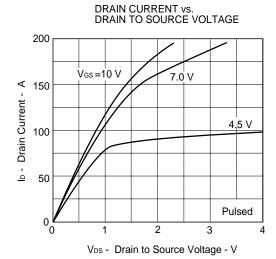


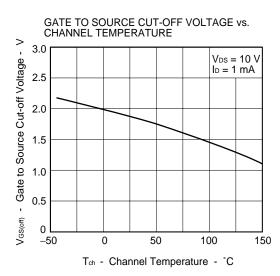


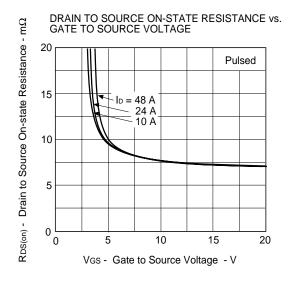
TEST CIRCUIT 2 GATE CHARGE



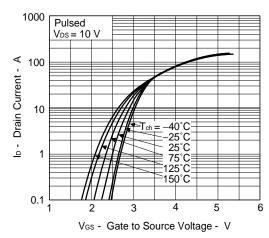
TYPICAL CHARACTERISTICS (TA = 25°C)



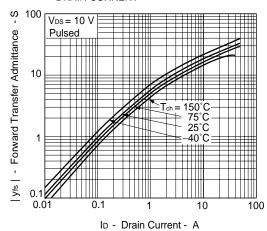


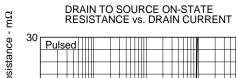


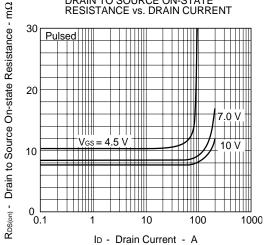
FORWARD TRANSFER CHARACTERISTICS

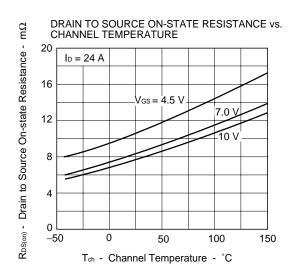


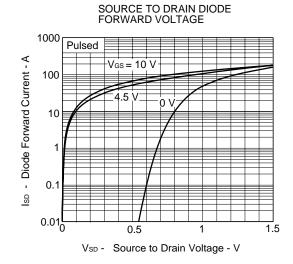
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

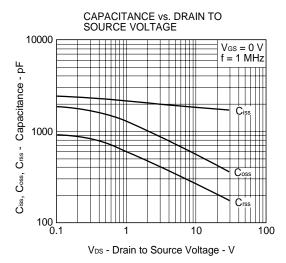


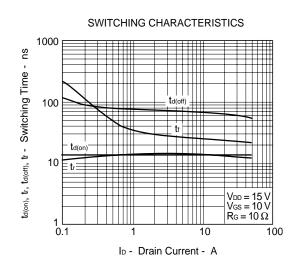


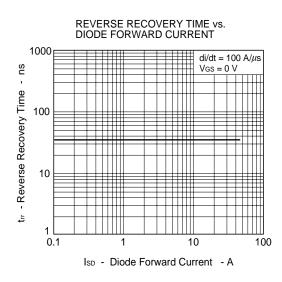


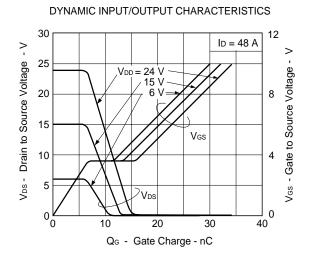


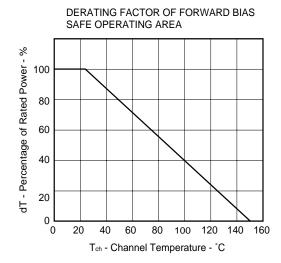


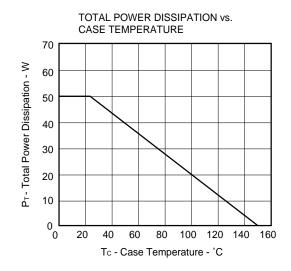




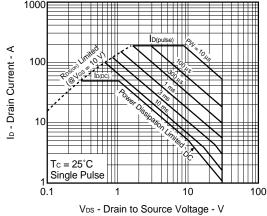


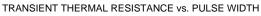


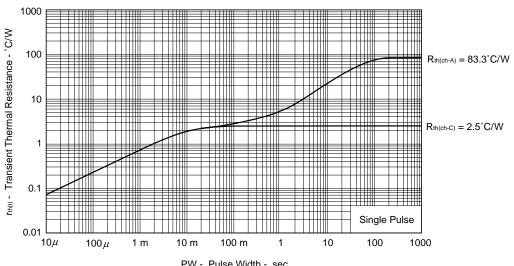




FORWARD BIAS SAFE OPERATING AREA 1000





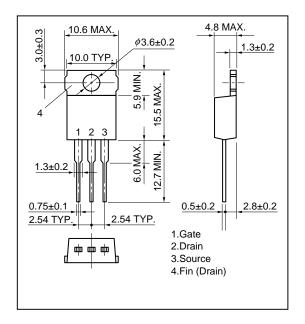


PW - Pulse Width - sec

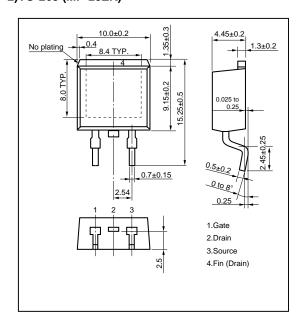


PACKAGE DRAWINGS (Unit: mm)

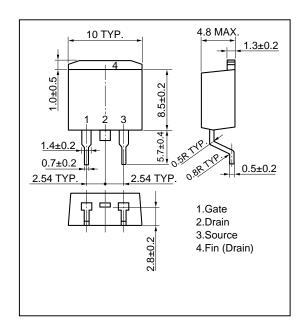
★ 1)TO-220AB (MP-25)



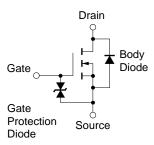
2)TO-263 (MP-25ZK)



★ 3)TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

2SK3424



[MEMO]

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